



DMN3016LDV

POWERDI

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _C = +25°C
30V	12mΩ @ V _{GS} = 10V	21A
30 V	17mΩ @ V _{GS} = 4.5V	18A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Power Management Functions
- Analog Switch

Features

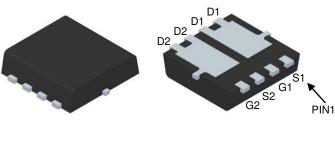
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

DUAL 30V N-CHANNEL ENHANCEMENT MODE MOSFET

Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

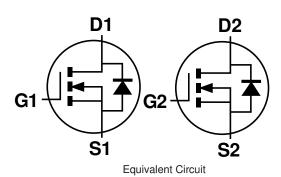
- Case: PowerDI3333-8 (Type UXC)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 ⁽²³⁾
- Weight: 0.072 grams (Approximate)



PowerDI3333-8 (Type UXC)

Top View





Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3016LDV-7	PowerDI3333-8 (Type UXC)	2000/Tape & Reel
DMN3016LDV-13	PowerDI3333-8 (Type UXC)	3000/Tape & Reel

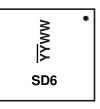
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



 $\begin{array}{l} SD6 = Product Type Marking Code \\ \hline \hline YYWW = Date Code Marking \\ \hline \overline{YY} = Last Two Digits of Year (ex: 16 for 2016) \\ WW = Week Code (01 to 53) \end{array}$



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current, $V_{GS} = 10V$ (Note 7) State $T_C = +25^{\circ}C$ State $T_C = +70^{\circ}C$			ID	21 17	А
Maximum Body Diode Forward Current (Note 6)		Is	2	А	
Pulsed Drain Current (380µs pulse, Duty cycle = 1%)			I _{DM}	70	А
Avalanche Current (L = 0.1mH) (Note 8)			I _{AS}	22	А
Avalanche Energy (L = 0.1mH) (Note 8)			E _{AS}	24	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)		PD	0.9	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Р	134	°C/W	
merinal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	78	C/W	
Total Power Dissipation (Note 6)		PD	1.8	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Б	70	°C/W	
merinal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	41		
Thermal Resistance, Junction to Case (Note 7)		R _{ejc}	15		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	Cymbol		1 JP	шах	Onit		
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V, I_{D} = 250 \mu A$	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}	-	-	1	μA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)						<u> </u>	
Gate Threshold Voltage	V _{GS(TH)}	1.4	-	2.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance			9.5	12		$V_{GS} = 10V, I_D = 7A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	14	17	mΩ	$V_{GS} = 4.5V, I_D = 7A$	
Diode Forward Voltage	V _{SD}	-	0.70	1.0	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)	·						
Input Capacitance	Ciss	-	1184	-		V_{DS} = 15V, V_{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	-	137	-	pF		
Reverse Transfer Capacitance	C _{rss}	-	107	-			
Gate Resistance	Rg	-	3.0	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	9.5	-			
Total Gate Charge (V _{GS} = 10V)	Qq	-	21	-	nC		
Gate-Source Charge	Q _{gs}	-	3.8	-	no	$V_{DS} = 15V, I_D = 12A$	
Gate-Drain Charge	Q _{gd}	-	4.1	-			
Turn-On Delay Time	t _{D(ON)}	-	4.5	-			
Turn-On Rise Time	t _R	-	3.3	-		$\label{eq:VDD} \begin{split} V_{DD} &= 15V, \ V_{GS} = 10V, \\ R_L &= 1.5\Omega, \ R_G = 3\Omega \end{split}$	
Turn-Off Delay Time	t _{D(OFF)}	-	14	-	ns		
Turn-Off Fall Time	tF	-	3.6	-	1		
Reverse Recovery Time	t _{RR}	-	9.3	-	ns		
Reverse Recovery Charge	Q _{RR}	-	2.5	-	nC	− I _F = 12A, di/dt = 500A/µs	

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).

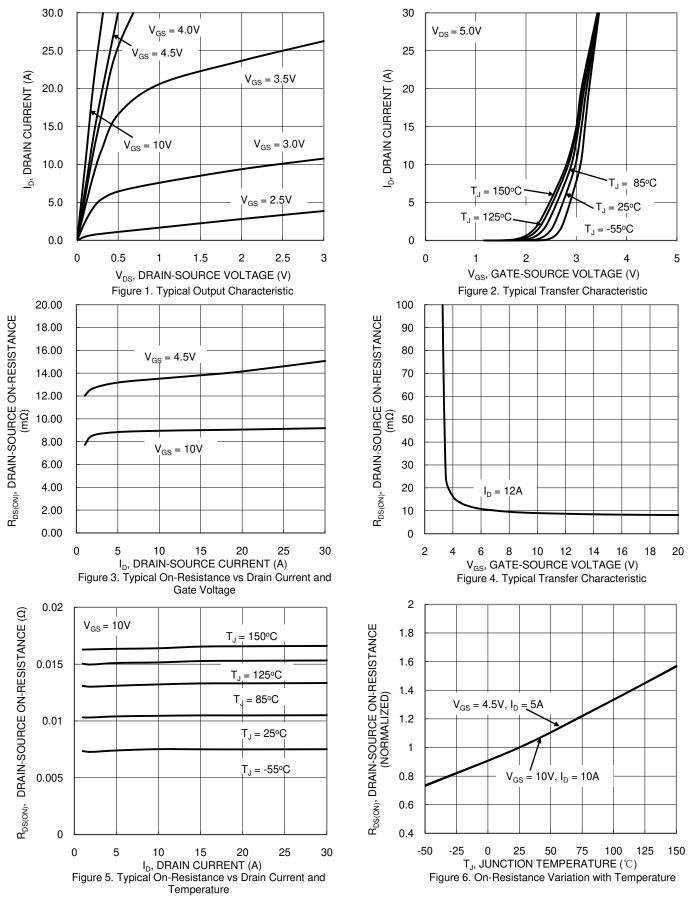
8. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep T_J = +25°C.

9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.



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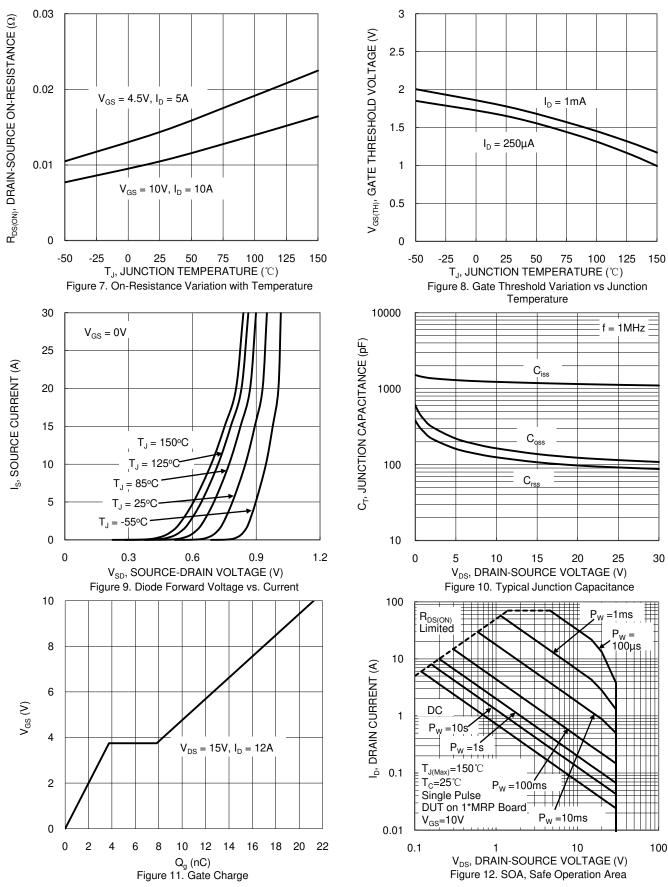


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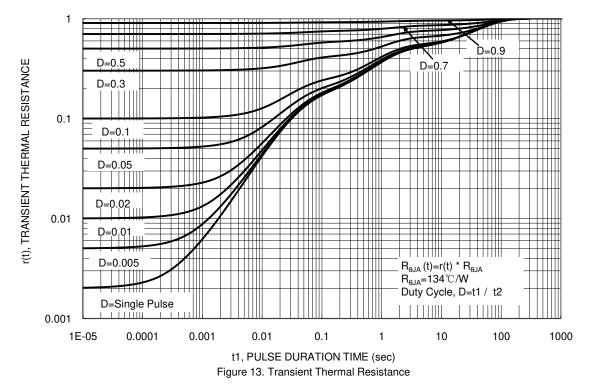
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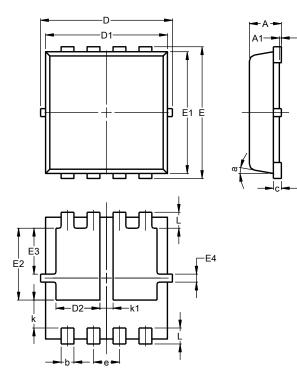




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UXC)

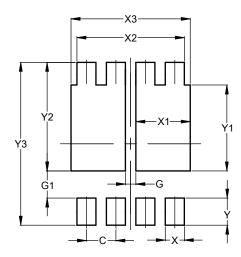


PowerDI3333-8						
(Type UXC)						
Dim	Min Max Ty					
Α	0.75	0.85	0.80			
A1	0.00	0.05	-			
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	0.90	1.30	1.10			
E	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	-	-	0.65			
L	0.30	0.50	0.40			
k	0.50	0.90	0.70			
k1	0.13	0.53	0.33			
а	0°	12°	10°			
All I	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UXC)



Dimensions	Value (in mm)			
С	0.650			
G	0.230			
G1	0.600			
Х	0.420			
X1	1.200			
X2	2.370			
X3	2.630			
Y	0.600			
Y1	1.900			
Y2	2.400			
Y3	3.600			



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